

# **GP2W3270YP0F**

## IrDA Compliant Transceiver Module 9.6 to 115.2 kb/s (SIR LP) Low Profile Low Consumption Current



#### ■ Description

The **GP2W3270YP0F** is an infrared transceiver module for IrDA ver. 1.4 (SIR LP).

The transceiver consisits of a pin-photo diode, infrared emitter and control IC in a single package.

This device is built in LED constant current circuit. This device have remote control transmission function (built in drive circuit).

#### **■**Features

1. Compliant with the IrDA 1.4 (SIR LP) Transmission speed: 9.6 to 115.2 kb/s Transmission distance: 20 cm

2. Small package

 $L7.6 \times W2.4 \times H1.5 mm$ 

- 3. Peak emission wavelength: 890 nm (Buit-in shared single LED for RC and IrDA)
- 4. Side view type
- 5. Soldering reflow type
- 6. Shield type
- 7. Low consumption current due to shutdown function (Consumption current at shutdown mode : Max.  $0.1~\mu A$ )
- 8. Operates from 2.4 to 3.6 V
- 9. With built in LED constant circuit
- 10. With remote control function (buit in drive circuit)
- 11. With V<sub>IO</sub> terminal

### ■ Agency approvals/Compliance

- 1. Compliant with IEC60825-1 class 1 eye safety standard
- 2. Compliant with RoHS directive (2002/95/EC)
- 3. Content status of six substances specified in "Management Methods for Control of Pollution Caused by Electronic Information Products Regulation" (popular name: *China RoHS*)

(Chinese: 电子信息产品污染控制管理办法)

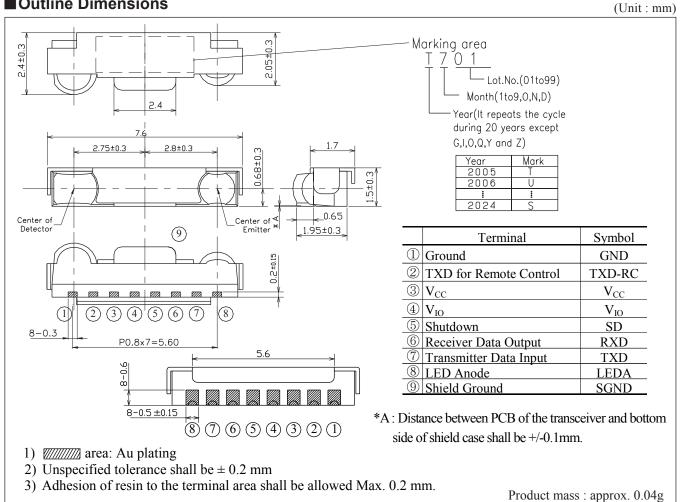
; refer to page 13 4. Lead (Pb) free device

#### ■Applications

- 1. Mobile equipment (Cellular phone, Pager, Smart phone, PDAs, Portable printer, etc.)
- 2. Digital imaging equipment (Digital camera, Photo imaging printer)
- 3. POS equipment

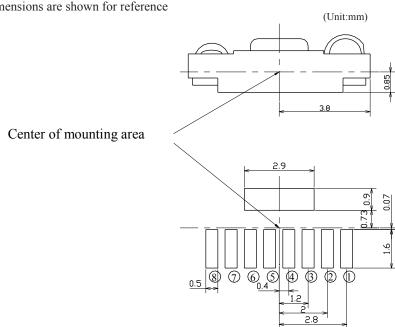


#### **■**Outline Dimensions



#### ■ Recommended PCB Foot Pattern

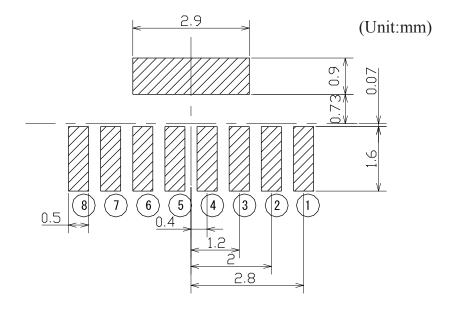
Dimensions are shown for reference





## ■ Recommended Size of Solder Creamed Paste (Reference)

Dimensions are shown for reference. Please open the solder mask as below so that the size of solder creamed paste for this device before reflow soldering must be as large as one of the foot pattern land indicated for reference.



Solder paste area



■ Absolute Maximum Ratings

(Ta=25°C)

| Parameter                 | Symbol             | Rating                    | Unit                   |
|---------------------------|--------------------|---------------------------|------------------------|
| Supply voltage            | V <sub>CC</sub>    | 0 to 6.0                  | V                      |
| VI/O Supply voltage       | V <sub>IO</sub>    | 0 to V <sub>CC</sub>      | V                      |
| LED Supply voltage        | $V_{LEDA}$         | 0 to 7.0                  | V                      |
| SD,TXD Input voltage      | $V_{SD}, V_{TXD}$  | 0 to V <sub>IO</sub> +0.3 | V                      |
| TXD-RC Input voltage      | V <sub>TXDRC</sub> | 0 to V <sub>IO</sub> +0.3 | V                      |
| *1 Peak forward current 1 | $I_{FM1}$          | 120                       | mA                     |
| *2 Peak forward current 2 | $I_{FM2}$          | 300                       | mA                     |
| Operating temperature     | Topr               | -40 to +85                | $^{\circ}$ C           |
| Storage temperature       | $T_{stg}$          | -40 to +85                | $^{\circ}\!\mathbb{C}$ |
| *3 Soldering temperature  | $T_{sol}$          | 260                       | $^{\circ}$ C           |

<sup>\*1</sup> Pulse width: 78.1µs, Duty ratio: 3/16 \*2 Pulse width: 17.9µs, Duty ratio: 1/4 \*3 Soldering reflow time: 10s

#### **■**Electrical Characteristics

 $(T_a=25^{\circ}C, V_{CC}=3.3V)$ 

|  | Liectrical Grandeteristics         |                        |   |                      |       |       |                  |  |  |  |
|--|------------------------------------|------------------------|---|----------------------|-------|-------|------------------|--|--|--|
|  | Parameter                          | Symbol                 | Rating  | MIN.                 | TYP.  | MAX.  | Unit             |  |  |  |
| Current consumption at no input signal |                                    | $I_{CC}$               | No input signal, output terminal open, $V_{IHSD}=0V$  |                      | 70    | 100   | μΑ               |  |  |  |
|  | rrent consumption<br>Shutdown mode | I <sub>CC-S</sub>      | No input signal, output terminal open, $V_{IHSD}=V_{CC}$  |                      | 0.001 | 0.1   | μΑ               |  |  |  |
| Hi                                     | gh level output voltage            | V <sub>OH</sub>        | $V_{CC}$ =2.4 to 3.6V, $I_{OH}$ =200 $\mu$ A*4  | V <sub>IO</sub> -0.4 | _     | _     | V                |  |  |  |
| Lo                                     | w level output voltage             | V <sub>OL</sub>        | $V_{CC}$ =2.4 to 3.6V, $I_{OL}$ =200 $\mu A^{*4}$   | _                    | _     | 0.4   | V                |  |  |  |
| Ris                                    | se time                            | $t_{\rm r}$            |   | _                    |       | 0.06  | μs               |  |  |  |
| Fal                                    | l time                             | $t_{\mathrm{f}}$       | $9.6 \text{kb/s} \le \text{BR} \le 115.2 \text{kb/s}, C_L = 10 \text{pF}, \ \phi \le 15^{\circ} *4$ | _                    |       | 0.06  | μs               |  |  |  |
| Lo                                     | w level pulse width                | $t_{\rm w}$            |   | 1.35                 | 2.25  | 3.3   | μs               |  |  |  |
| Ma                                     | ximum reception distance           | L                      | $9.6$ kb/s $\leq$ BR $\leq$ 115.2kb/s, $C_L$ =10pF, $\phi \leq$ 15° *4                              | 21                   | _     | _     | cm               |  |  |  |
| Inp                                    | out irradiance                     | Ee                     | $9.6$ kb/s $\leq$ BR $\leq$ 115.2kb/s, $C_L$ =10pF, $\phi \leq$ 15° *4                              | _                    |       | 0.081 | W/m <sup>2</sup> |  |  |  |
| Re                                     | ceiver wakeup Latency              | t <sub>l</sub>         |   | _                    |       | 200   | μs               |  |  |  |
| Re                                     | ceiver wakeup time                 | $t_{\rm sdw}$          | No input signal   | _                    | _     | 200   | μs               |  |  |  |
|  | Radiant intensity                  | $I_{E}$                |   | 5.5                  |       | 28    | mW/sr            |  |  |  |
|  | LED peak current                   | $I_{LED}$              | BR=115.2kb/s, $\phi \le 15^{\circ}$ ,   | 43                   | 60    | 80    | mA               |  |  |  |
| IrDA                                   | Rise time                          | t <sub>r</sub>         | $V_{\text{IHTXD}} = 2.8 V^{*5}$   |                      | _     | 0.6   | μs               |  |  |  |
| Ξ                                      | Fall time                          | $t_{\mathrm{f}}$       |   |                      |       | 0.6   | μs               |  |  |  |
|  | Peak emission wavelength           | $\lambda_{\mathrm{p}}$ |   | 875                  | 890   | 900   | nm               |  |  |  |
|  | Maximum optical pulse width        | $T_{OPWM}$             | TXD pin stuck High  | 30                   | 80    | 250   | μs               |  |  |  |
|  | Transmit distance                  | $L_{RC}$               |   | 4                    | _     | _     | m                |  |  |  |
|  | Radiant intensity                  | I <sub>ERC</sub>       | f=40kHz,duty=25%, $\phi$ =0°, $V_{IHTXD}$ =2.8 $V^{*5}$   |                      | _     | 100   | mW/sr            |  |  |  |
| RC                                     | LED peak current                   | I <sub>LEDRC</sub>     |   |                      | 200   | 260   | mA               |  |  |  |
|  | Peak emission wavelength           | $\lambda_{ m p}$       |   |                      | 890   | _     | nm               |  |  |  |
|  | Maximum optical pulse width        | T <sub>OPWM</sub>      | TXD pin stuck High  | 30                   | 80    | 250   | μs               |  |  |  |

<sup>\*4</sup> Refer to Fig.2, 3, 4 \*5 Refer to Fig.5, 6, 7



# **■**Recommended Operating Conditions

| Parameter                            | Symbol               | Conditions                        | Rating                           | Unit                   |
|--------------------------------------|----------------------|-----------------------------------|----------------------------------|------------------------|
| Supply voltage                       | V <sub>CC</sub>      |                                   | 2.4 to 3.6                       | V                      |
| V <sub>IO</sub> voltage              | $V_{IO}$             |                                   | $1.5$ to $V_{CC}$                | V                      |
| LED Supply voltage                   | $V_{LEDA}$           |                                   | V <sub>CC</sub> -0.5 to 6.5      | V                      |
| Operating temperature                | Topr                 |                                   | -25 to +85                       | $^{\circ}\!\mathbb{C}$ |
| Data rate                            | BR                   |                                   | 9.6 to 115.2                     | kb/s                   |
| SD terminal input voltage Logic High | $V_{IHSD}$           | Shutdown mode, $2.4V \leq V_{IO}$ | $V_{CC} \times 0.67$ to $V_{CC}$ | V                      |
| SD terminal input voltage Logic Low  | $V_{ILSD}$           | Normal mode, $2.4V \leq V_{IO}$   | $0.0$ to $V_{CC} \times 0.33$    | V                      |
| TDX high level input voltage         | V <sub>IHTXD</sub>   | LED ON *6                         | $V_{IO} \times 0.67$ to $V_{IO}$ | V                      |
| TDX low level input voltage          | V <sub>ILXTD</sub>   | LED OFF *6                        | $0.0$ to $V_{IO} \times 0.33$    | V                      |
| TDX-RC high level input voltage      | V <sub>IHTXDRC</sub> | w.c                               | $V_{IO} \times 0.67$ to $V_{IO}$ | V                      |
| TDX-RC low level input voltage       | V <sub>ILXTDRC</sub> | LED OFF *6                        | 0.0 to V <sub>IO</sub> ×0.33     | V                      |

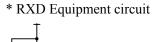
<sup>\*6</sup> Refer to Fig.7



#### **■**Truth Table

| Mode                     | SD | TXD | TXD-RC | Input signal | LED       | RXD     |
|--------------------------|----|-----|--------|--------------|-----------|---------|
| N. I. I                  |    | 0   | 0      | No           | Off       | 1       |
| Normal mode              | 0  | 0   | 0      | IrDA         | Off       | 0**     |
| IrDA operation           | 0  | 0   | 1      | *            | On(60mA)  | 0       |
|                          | 0  | 1   | 0      | *            | On(60mA)  | 0       |
| Remote control operation | 1  | 0   | 1      | *            | On(200mA) | pull-up |
| Shutdown mode            | 1  | 0   | 0      | *            | Off       | pull-up |

<sup>\*</sup> Don't care



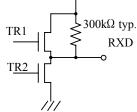
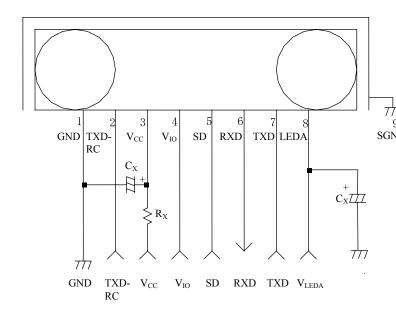


Fig.1 Recommended External Circuit



| Components circuit | Recommended values |
|--------------------|--------------------|
| $C_{X}$            | 1μF/6.3V(Note)     |
| $R_{X}$            | 1 to 15 Ω          |

(Note) Please choose the most suitable Cx according to the noise level and noise frequency of power supply.

SGND Depending on noise level and noise frequency of power supply, Cx does not work well. There are cases that some pulse noises from RXD other than signal will occur in certain communication area.

Please check by finish product that there are no problem at all communication area and data rate. If there are any problem, please check by inserting  $R_X$  (1 to  $15\Omega$ )in the circuit drawing. Although there is no problem to distribute the voltage supply of Vcc,  $V_{IO}$ , and  $V_{LED}$  terminal, please apply the voltage to Vcc terminal first.

<sup>\*\*</sup> The pulse width is constant without depending on the transmission rate and the light intensity of input signal.



## Fig.2 Input Signal Waveform(Receiver side)



 $9.6kb/s \le BR(=1/T_1) \le 115.2kb/s$  $1.41 \mu s \le T_2 \le 22 \mu s$ 

Fig.3 Output Waveform Specification(Receiver side)

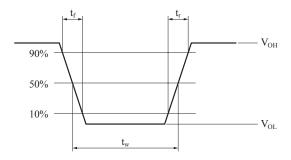
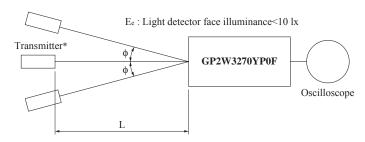


Fig.4 Standard Optical System(Receiver side)



 $\boldsymbol{\varphi}$  : Indicates horizontal and vertical directions.

<sup>\*</sup>Transmitter shall use GP2W3270YP0F ( $\lambda_p$ =890nm TYP.) which is adjusted the radiation intensity at 3.6mW/sr.



Fig.5 Output Waveform Specification(Transmitter side)

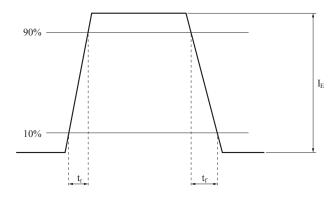


Fig.6 Standard Optical System(Transmitter side)

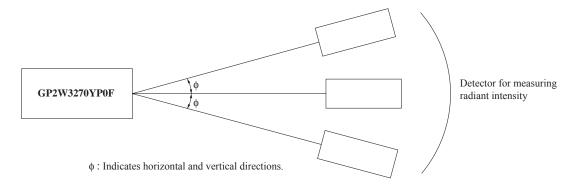
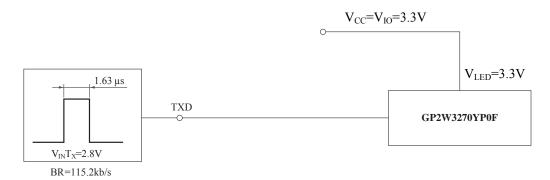


Fig.7 Recommended Circuit of Transmitter side





#### ■Notes

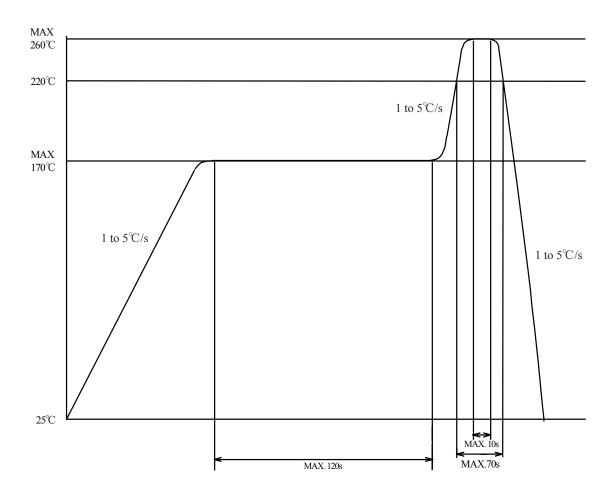
- (1) When the system (program) is designed, the Turn Around Time shall be secured by considering 500 μs or more that is specified to IrDA.
  - Then, this Turn Around Time means the time when this device does not temporarily detect the signal light, since the transmitted light form the transceiver reaches the detector side of the transceiver.
- (2) As it is necessary 200 μs or more (at Ta =25 °C, no input signal) to return from shut-down mode to readyoperation mode, please consider this point at the system (program) designing. Also, please confirm thoroughly the operation in actual application.
- (3) When there is much external disturbing light source is located near this transceiver and the detector face resceiver much external disturbing light, there is case that the pulse other than signal output is generated as noise on output terminal of this transceiver. Please consider the lay-out and structure to reduce disturbing light on the detector face.
- (4) In case that this sensor is adopted in IR communication system, please use it according to the signal method which is specified by [Serial Infrared Physical Layer Link Specification Version 1.4] published by Infrared Data Association. False operation may happen if the different signal method is used.
- (5) In circuit designing, make allowance for the degradation of light emitting diode output that results from long continuous operation. (50 % degradation/5 years)



#### **■**Soldering Method

#### 1. In case of solder reflow

Please carry out only two times soldering at the temperature and the time within the temperature profile as shown in the figure below. Reflow interval shall be within 3 days under conditions, 10 to 30°C, 70%RH or less.



#### 2. Other precautions

An infrared lamp used to heat up for soldering may cause a localized temperature rise in the resin. So keep the package temperature within that specified in Item 1. Also avoid immersing the resin part in the solder. Even if within the temperature profile above, there is the possibility that the gold wire in package is broken in case that the deformation of PCB gives the affection to lead pins. Please use after confirming the conditions fully by actual solder reflow machine.

#### 3. Soldering

- Soldering iron shall be less than 25W, and temperature of point of soldering iron shall use at 350°C or less.
- Soldering time shall be within 5s.
- Soldered product shall treat at normal temperature.



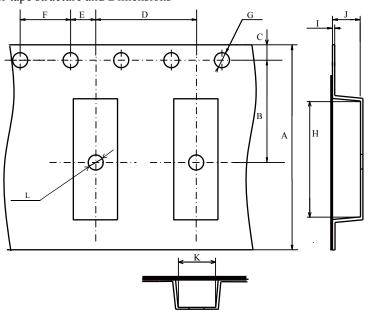
# ■Package specification

# ● Tape and Reel package 2000 pcs/reel

#### Taping materials

| Name         | Material | Countermeasure for ESD |
|--------------|----------|------------------------|
| Reel         | PPE      | Coped(conductivity)    |
| Carrier tape | PC       | Coped(conductivity)    |
| Cover tape   | PET      | Coped(conductivity)    |

#### Carrier tape structure and Dimensions

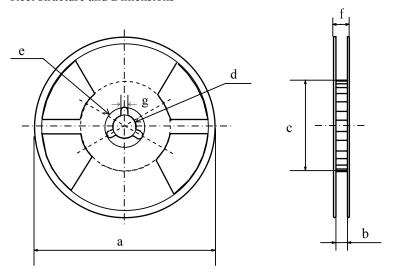


| Dimension List | (Unit : mm) |
|----------------|-------------|
|----------------|-------------|

| A                          | В         | С         | D       | Е       | F                             |
|----------------------------|-----------|-----------|---------|---------|-------------------------------|
| 16.0±0.3                   | 7.5±0.1   | 1.75±0.10 | 8.0±0.1 | 2.0±0.1 | 4.0±0.1                       |
| G                          | Н         | I         | J       | K       | L                             |
| $\phi \ 1.5^{+0.1}_{-0.0}$ | 7.85±0.10 | 0.32±0.05 | 1.8±0.1 | 2.7±0.1 | $\phi \ 1.50^{+0.25}_{-0.00}$ |

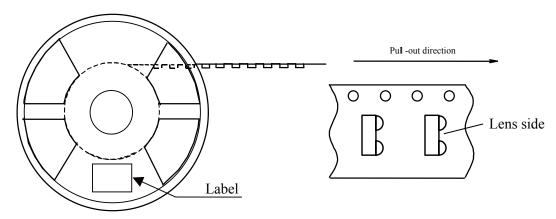


#### Reel structure and Dimensions



| Dimension List (Unit: |          |         |          |  |  |  |  |
|-----------------------|----------|---------|----------|--|--|--|--|
| a                     | b        | c       | d        |  |  |  |  |
| 330±2                 | 17.5±1.0 | 100±1   | 13.0±0.2 |  |  |  |  |
| e                     | f        | g       |          |  |  |  |  |
| 21.0±0.8              | 22.4±1.0 | 2.0±0.5 |          |  |  |  |  |

### Direction of product insertion





#### Cleaning Instructions

#### Solvent cleaning:

Solvent temperature 45°C or less, Immersion for 3 min or less

#### Ultrasonic cleaning:

The effect to device by ultrasonic cleaning differs by cleaning bath size, ultrasonic power output, cleaning time, PCB size or device mounting condition etc.

Please test it in actual using condition and confirm that doesn't occur any defect before starting the ultrasonic cleaning. The cleaning shall be carried out with solvent below.

#### Recommended Solvent materials:

Ethyl alcohol, Methyl alcohol, Isopropyl alcohol

#### **●**Presence of ODC etc.

This product shall not contain the following materials.

And they are not used in the production process for this product.

Regulation substances: CFCs, Halon, Carbon tetrachloride, 1.1.1-Trichloroethane (Methylchloroform)

Specific brominated flame retardants such as the PBB and PBDE are not used in this product at all.

• The RoHS directive (2002/95/EC)

This product complies with the RoHS directive (2002/95/EC).

Object substances: lead, cadmium, hexavalent chromium, polybrominated biphenyls (PBB) and polybrominated diphenyl ethers (PBDE)

• Content of six substances specified in "Management Methods for Control of Pollution Caused by Electronic Information Products Regulation" (Chinese: 电子信息产品污染控制管理办法)

|                                    | Toxic and hazardous substances |                 |                 |   |                                      |   |
|------------------------------------|--------------------------------|-----------------|-----------------|---|--------------------------------------|---|
| Category                           | Lead (Pb)                      | Mercury<br>(Hg) | Cadmium<br>(Cd) | Hexavalent<br>chromium<br>(Cr <sup>6+</sup> ) | Polybrominated<br>biphenyls<br>(PBB) | Polybrominated<br>diphenyl ethers<br>(PBDE) |
| Infrared data communication device | 1                              | <b>\</b>        | 1               | 1   | <b>√</b>                             | 1   |

<sup>✓:</sup> indicates that the content of the toxic and hazardous substance in all the homogeneous materials of the part is below the concentration limit requirement as described in SJ/T 11363-2006 standard.



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